Title: ELECTRODE, METHOD FOR MANUFACTURING
THE SAME AND SEMICONDUCTOR DEVICE USING THE SAME
Inventors: Tatsuo NAKAYAMA, et al.
Atty. Dkt. No. 040373-0381

Fig. 1

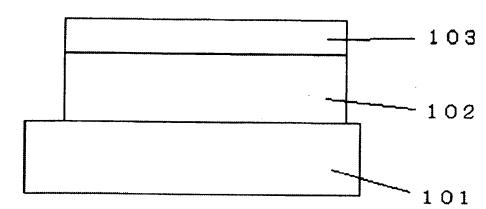


Fig. 2

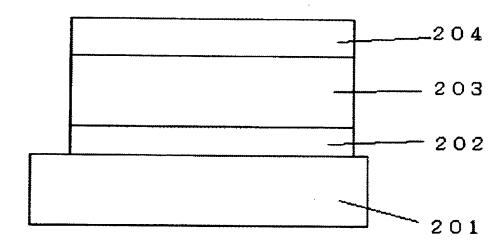
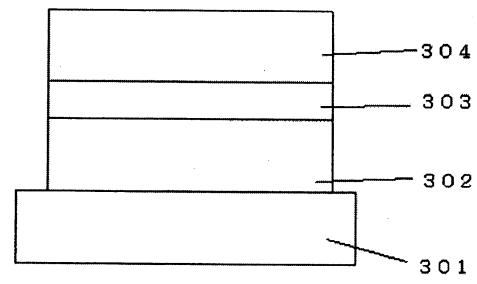
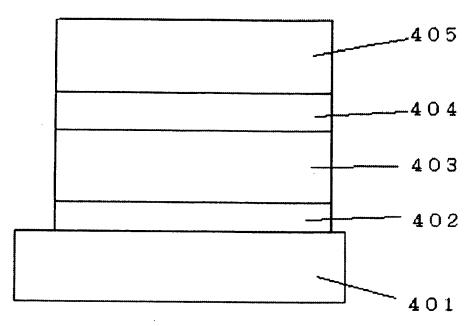


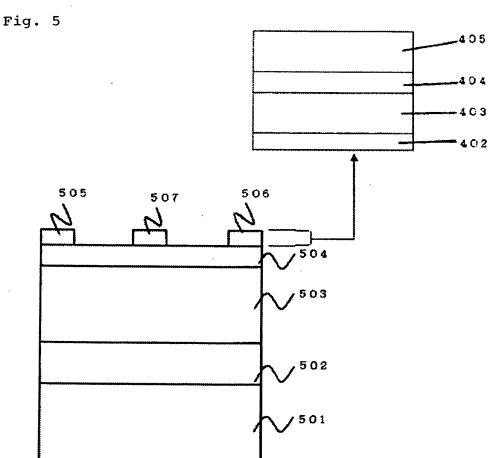
Fig. 3



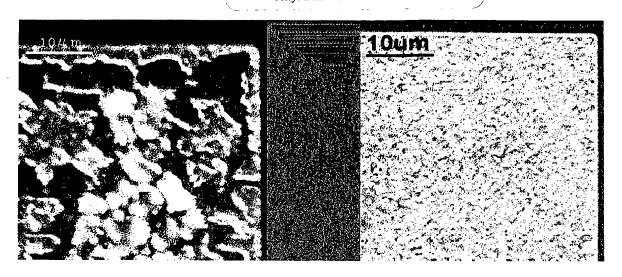
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Fig. 4





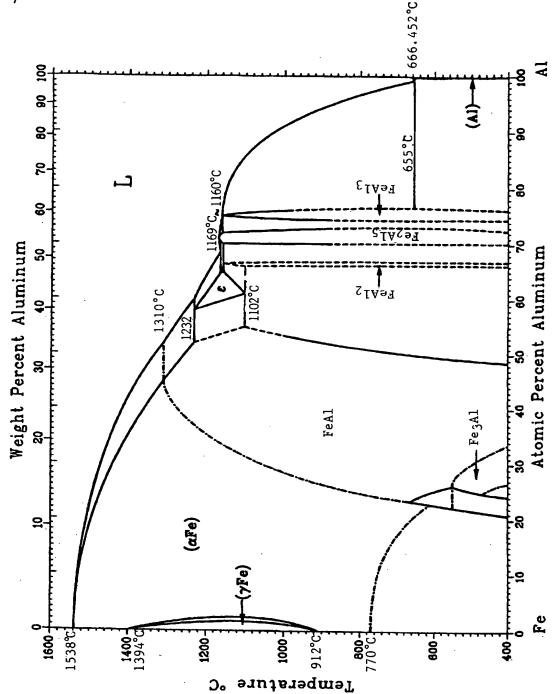
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Fe-Al Phase Diagram



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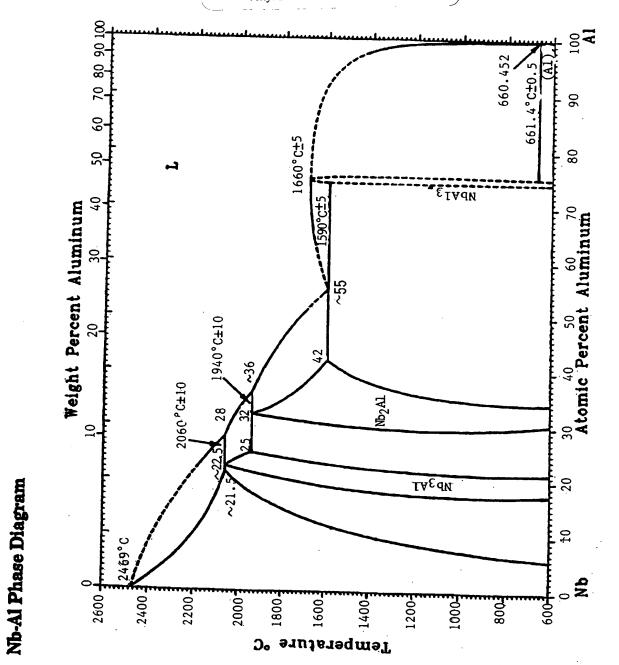


Fig. 9

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